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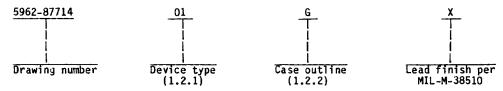
DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

DESC FORM 193

MAY 86



- 1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of $\overline{\text{MIL}}$ -STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".
 - 1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device types. The device types shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01 02	OP14A OP14B	Dual matched high performance operational amplifiers Dual matched high performance operational amplifiers

1.2.2 <u>Case outlines</u>. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
G P	A-1 (8-lead can) $70-5/70-99$ D-4 (8-lead 1/4" x 3/8"), dual-in-line package 900

1.3 Absolute maximum ratings.

Supply voltage	±22 V
Power dissipation (Pn)	500 mW
Differential input voltage	±30 V
Input voltage	Supply voltage
Output short-circuit duration	Indefinite
Storage temperature range	-65°C to +150°C
Lead temperature range (soldering, 60 seconds)	+300°C
Junction temperature (T_1)	-65°C to +150°C

1.4 Recommended operating conditions.

Supply voltage (Mar)	+15 V
Supply voltage (V _{CC}) Ambient operating temperature range	-13 V
Ambient operating temperature range	-55 C to +125 C

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2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
 - REQUIREMENTS
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
- 3.2.1 Terminal connections and logic diagrams. The terminal connections and logic diagrams shall be as specified on figure 1.
 - 3.2.2 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

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Test	 Symbol 	Conditions -55°C < TA < +17 unless otherwise spe			「A < +125°C type vise specified		 Group A subgrou 		nits	Uni
			V _S = ±15	ν΄	!		 	 Min	Max	i i
Input offset voltage	V _{OS}	 R _S <u><</u> 20	kΩ			01	1	-0.75	0.75	l mV
		!			1		2,3	-1.5	(1.5)	
Input offset current	IOS	! !			ļ		1	-5	5	l nA
	<u> </u>	!]					2,3	-10	10	!
Input bias current	IB) 			ļ	,	1	-50	50	l nA
							2,3	-60	60	<u> </u>
Input voltage range	I VR	1/			ļ		1	±10		V
	<u> </u>	! 			<u></u>		2,3	±10		
Common mode rejection ratio	CMRR	VCM = IV	R = ±10 V				1	85		dB
		RS < 20 1					2,3	80		
Power supply rejection ratio	PSRR	R _S < 20	kΩ V to ±20 V				1	<u> </u>	60	uV/
		VS = 15	V (0 ±20 V				2,3		60	
Output voltage swing	v _o	$R_{L} \geq 2 \text{ ks}$	Ω			-	4	±12		٧
	<u> </u>			····		-	5,6	±12		
arge signal voltage gain	A _{VO}	R _{L > 2 ks}	Ω $V_0 = *10$	٧	ļ	-	4	100		V/m
							5,6	50		
Power supply current	ISY	No load (each amplif C	ier	 		1		3	mA
Power dissipation	IP _D	 No load (T _A = +25	each amplif °C	ier		-	1		90	mW
Channel separation	lcs					•	7	100		dВ
Output short circuit	I _{SC} -						1	-60		mA
	I _{SC} +	 			į		i 2,3		60	
See footnotes at end of	table.				<u> </u>		•	<u> </u>		
MILITARY D			SIZE		7268		WG NO. 5962	2-87714		
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		Electrical performance characte	130103 -	continued.			
Test	Symbol Symbol	Conditions	Device	Group A	Lin	 Unit	
		Conditions $-55^{\circ}C \leq T_{A} \leq +125^{\circ}C$ unless otherwise specified $V_{S} = \pm 15 \text{ V}$	type 	subgroups 	Min	Max	
Input resistance differential mode	RIN	<u>2</u> /	01	1 1	2.0		Μ Ω
Rise time	 t _r 	$ A_{VCL} = +1, V_{IN} = 50 \text{ mV} R_L \ge 2 \text{ k}\Omega, R_S = 50\Omega, C_L = 50 \text{ pF} $	T 	9		350	ns
Overshoot	los	$A_{VCL} = +1$, $V_{IN} = 50 \text{ mV}$ $R_{L} > 2 \text{ k}\Omega$, $R_{S} = 50\Omega$, $C_{L} = 50 \text{ pF}$		9		10	% %
Slew rate	SR	$ R_{L} \ge = 2 \text{ k}\Omega, R_{S} = 50 \text{ k}\Omega$ $ C_{L} = 100 \text{ pF}$	† ! !	7 7 	0.25		 V /μs
Bandwidth	BW	A _{VCL} = +1 <u>3/</u>	 	7	1		MHZ
Large signal bandwidth	LSBW	V ₀ = 20 V _{p - p} 4/	T	7	4		kHz
Input offset voltage match	Delta		Ţ	1 1	-1	1	l mV
	Vos		<u> </u>	2,3	-1.5	1.5	<u> </u>
Common mode rejection	Delta	$V_{CM} = \pm 10 \text{ V}, R_S \leq 100\Omega$!	1 1	94		 dB
ratio match	CMRR 	1		2,3	90 i	<u> </u>	! 1

See footnotes at end of table.

MILITARY DRAWING	SIZE	67268	DWG NO.		
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02	1 2,3 1 2,3 1 2,3 1 2,3 1 2,3	Min -5 -6 -25 -50 -100 -200 ±10	Max 5 1 6 1 25 1 100 1 200	mV nA
02 	2,3	-6 -25 -50 -100	25 50 100	T nA
	2,3	-25 -50 -100	50	Γ
	2,3	-50 -100 -200	50 1 100	Γ
	2,3	-100 -200	100	nA
 	2,3	-200	1	nA
 	1		200	
 	T	±10	Ť T	<u>i</u>
 	23		<u> </u>	įν
	+ -,-	±10	<u> </u>	<u> </u>
1	1 1	70	ļ	dB
! -	2,3	70	<u> </u>	<u> </u>
<u> </u>	1		150	 uV/\
! <u> </u>	2,3	<u> </u>	150	
<u> </u>	4	±12		\ v
<u> </u>	5,6	±10	<u> </u>	<u> </u>
ļ	4	50	<u> </u>	 V/m
! <u> </u>	5,6	25		<u> </u>
† - -	1	! 	3	l mA
 	1	 	90	l mW
Ť	7	80		l dB
Ţ	1	-60		l mA
 	2,3		60	T
		5,6 4 5,6 1 1 1 1 1	4	1



							
TA	BLE I.	Electrical performance character	ristics -	Continued.			
Test	Symbol	Conditions Conditions To see the conditions Conditions To see the conditions To see the conditions Conditions To see the condition	Device type	Group A	Limits		 Unit
	<u> </u>	<u> </u>	i	<u>i</u>	Min	Max	<u> </u>
Input resistance differential mode	 R _{IN}	<u> </u>	 02 	1 1	1.0	İ	 Μ Ω
Rise time	tr			9		350	ns
Overshoot	 0S 	$ A_{VCL} = +1, V_{IN} = 50 \text{ mV}$ $ R_{L} \ge 2 \text{ k}\Omega, R_{S} = 50\Omega,$ $ C_{L} = 50 \text{ pF}$	†] 9 		10	%
Slew rate	SR	$ R_L\rangle = 2 k\Omega$, $R_S = 50 k\Omega$ $ C_L\rangle = 100 pF$	† 	7	0.25		 V /μs
Bandwidth	BW		†	7	1		MHz
Large signal bandwidth	LSBW	$ V_0 = 20 V_p - p \frac{4}{2}$	†] 7 	4		kHz
Input offset voltage	Delta V _{OS}	 	1	1 1	-1	1	mV
	,02	İ	<u> </u>	2,3	-1.5	1.5	<u> </u>
Common mode rejection ratio match	 Delta CMRR	$V_{CM} = \pm 10 \text{ V, } R_{S} \leq 100\Omega$	1		94		dB
, acro materi	CITER	! 	1] 2.3	90] -

^{1/} IVR is guaranteed by CMRR test.

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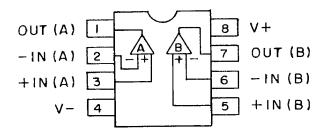
 $^{2/}R_{IN}$ is guaranteed by I_B test. $R_{IN} = 4KT/qI_B$ where KT/q = .026 V at +25°C.

^{3/} Bandwidth is guaranteed by t_r test. BW = .35/ t_r .

 $[\]underline{4}$ / Large signal bandwidth is guaranteed by SR test. LSBW = SR/2/(V_{peak}).

Device types 01 and 02

Case P



Case G

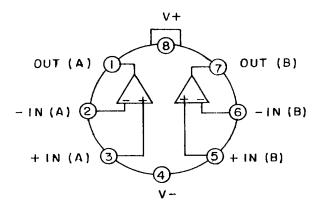


FIGURE 1. Terminal connections and logic diagrams.

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- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening.</u> Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test (method 1015 of MIL-STD-883).
 - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method $\frac{5005}{5005}$ of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 8, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

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TABLE II. Electrical test requirements.

 MIL-STD-883 test requirements	 Subgroups (per method 5005, table I)
 Interim electrical parameters (method 5004)	1
 Final electrical test parameters (method 5004)	 1*,2,3,4,5,6
Group A test requirements (method 5005)	1,2,3,4,5,6, 7,9
 Groups C and D end-point electrical parameters (method 5005)	1

^{*}PDA applies to subgroup 1.

- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
- 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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6.4 Approved source of supply. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1</u> /
5962-8771401GX	06665	OP14AZ/883
5962-8771401PX	06665	OP14AJ/883
5962-8771402GX	06665	OP14BZ/883
5962-8771402PX	1 06665	OP14BJ/883

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

06665

Vendor name and address

Precision Monolithics, Incorporated 1500 Space Park Drive P.O. Box 58020 Santa Clara, CA 95050

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DEFENSE ELECTRONICS SUPPLY CENTER
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